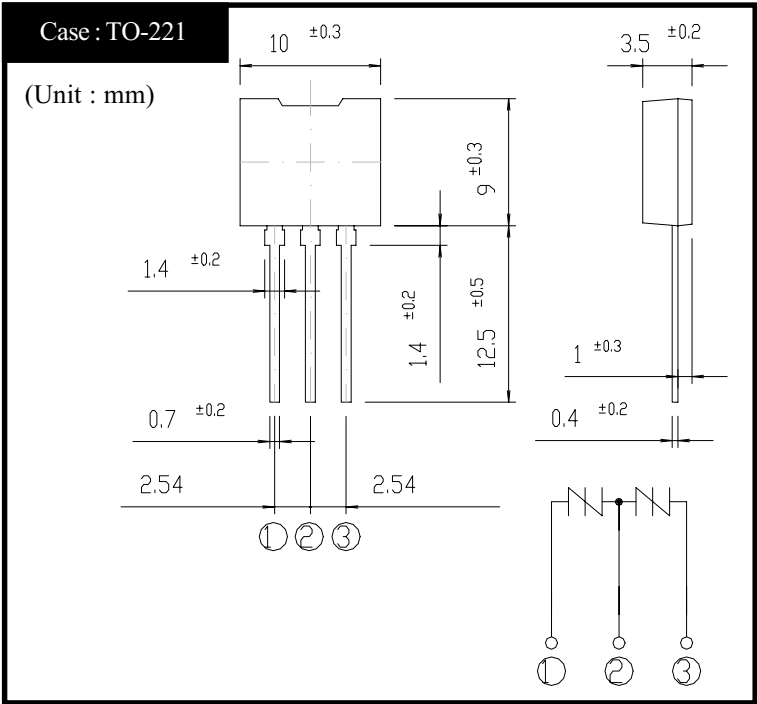


KT10R25

OUTLINE DIMENSIONS



RATINGS

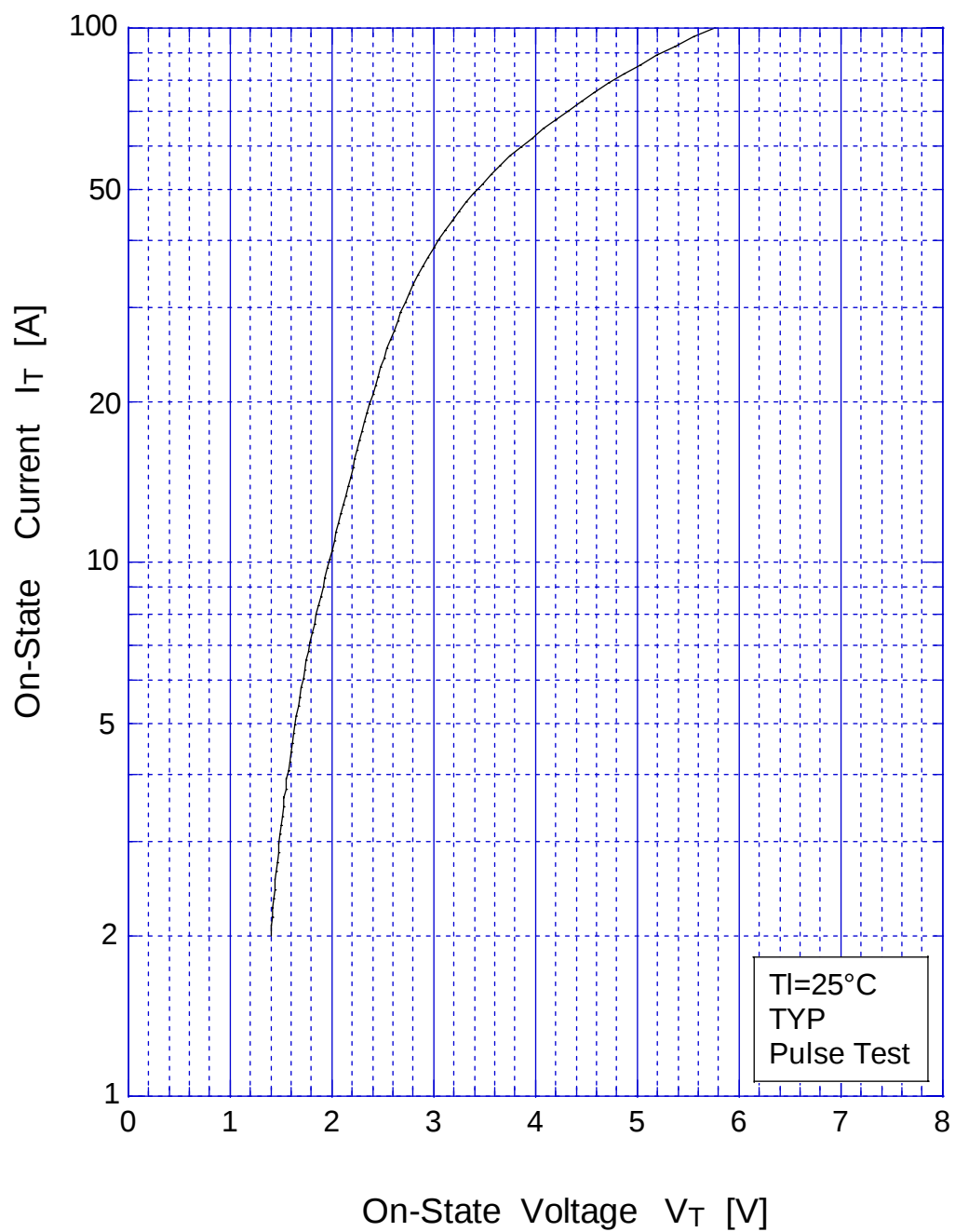
●Absolute Maximum Ratings (If not specified, Tl=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-40~125	°C
Junction Temperature	Tj		125	°C
Maximum Off-State Voltage	V _{DRM}		190	V
Surge On-State Current	I _{TSM}	10/1000 μ s, Non-repetitive	100	A

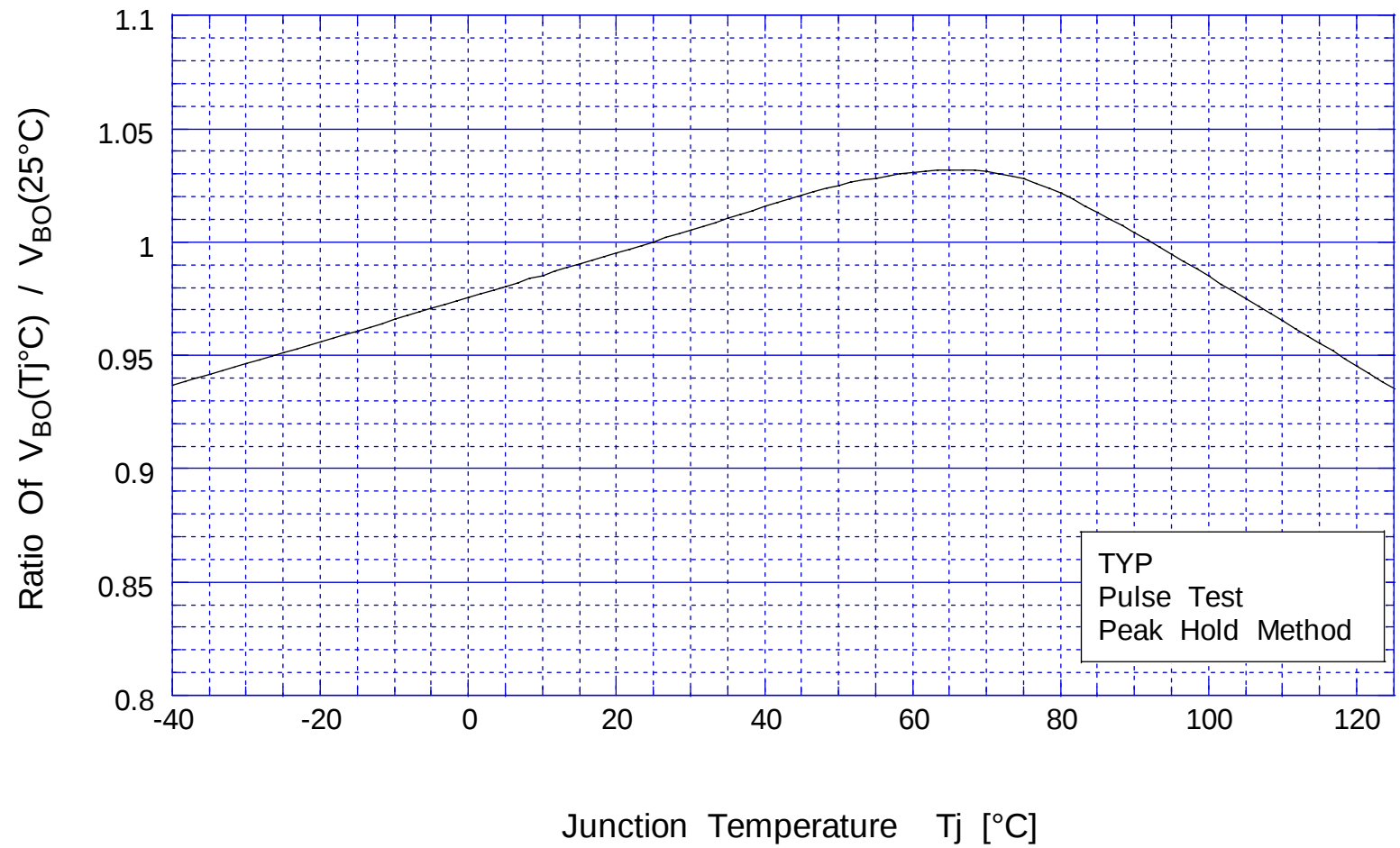
●Electrical Characteristics (If not specified, Tl=25°C)

Item	Symbol	Conditions	Ratings	Unit
Breakover Voltage	V _{BO}	Pulse measurement (Peak hold)	Min 220	V
Off-State Current	I _{DRM}	V _D = V _{DRM}	Max 10	μ A
Holding Current	I _H	Pulse measurement	Min 100	mA
On-State Voltage	V _T	I _T = 2A	TYP 1.4	V
Junction Capacitance	C _j	f = 1kHz, V _D = 50VDC OSC = 1Vrms	Max 90	pF
Clamping Voltage	V _{CL}	dv/dt = 100V/ μ s	Max 290	V

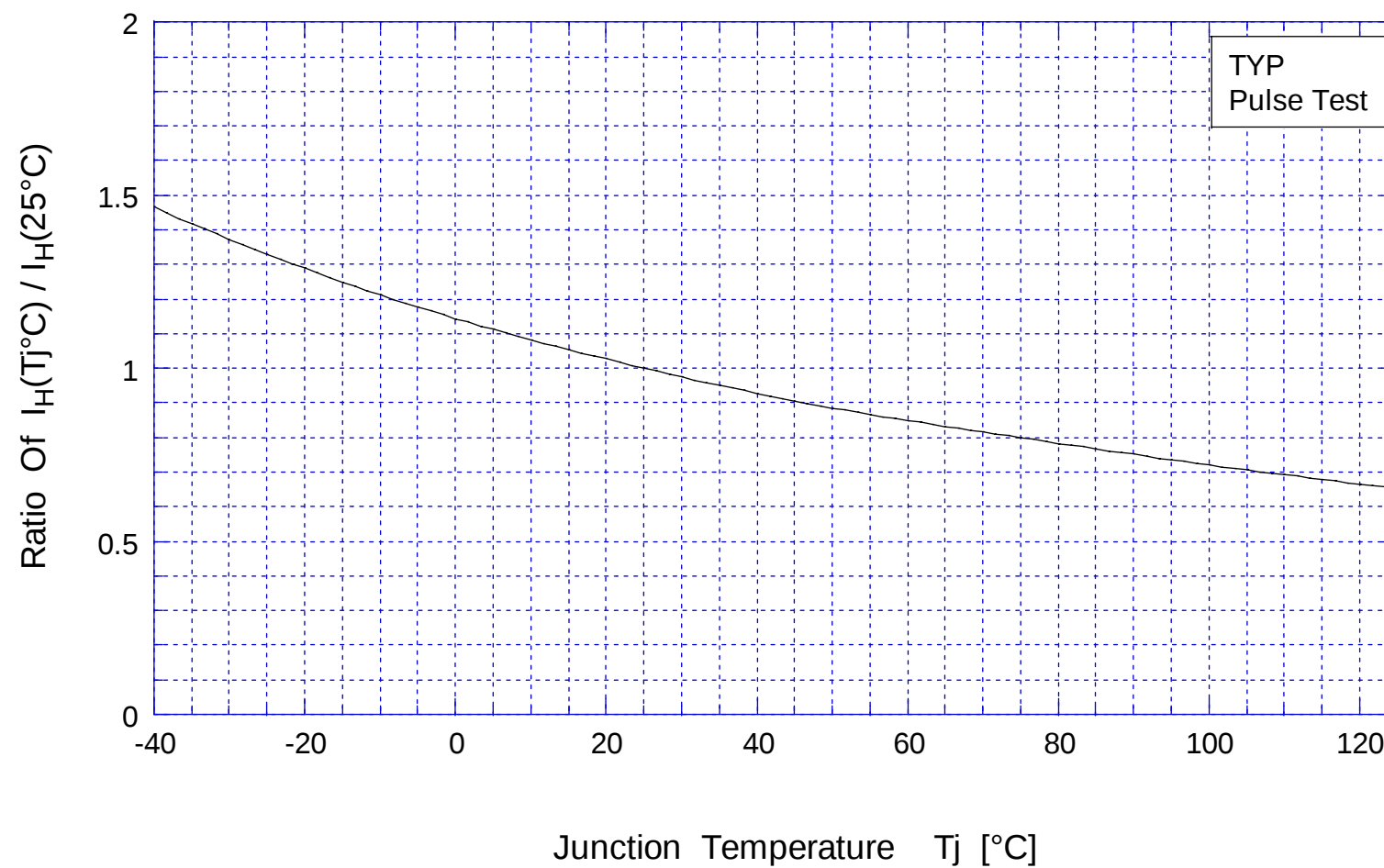
KT10R25 On-State Voltage vs On-State Current



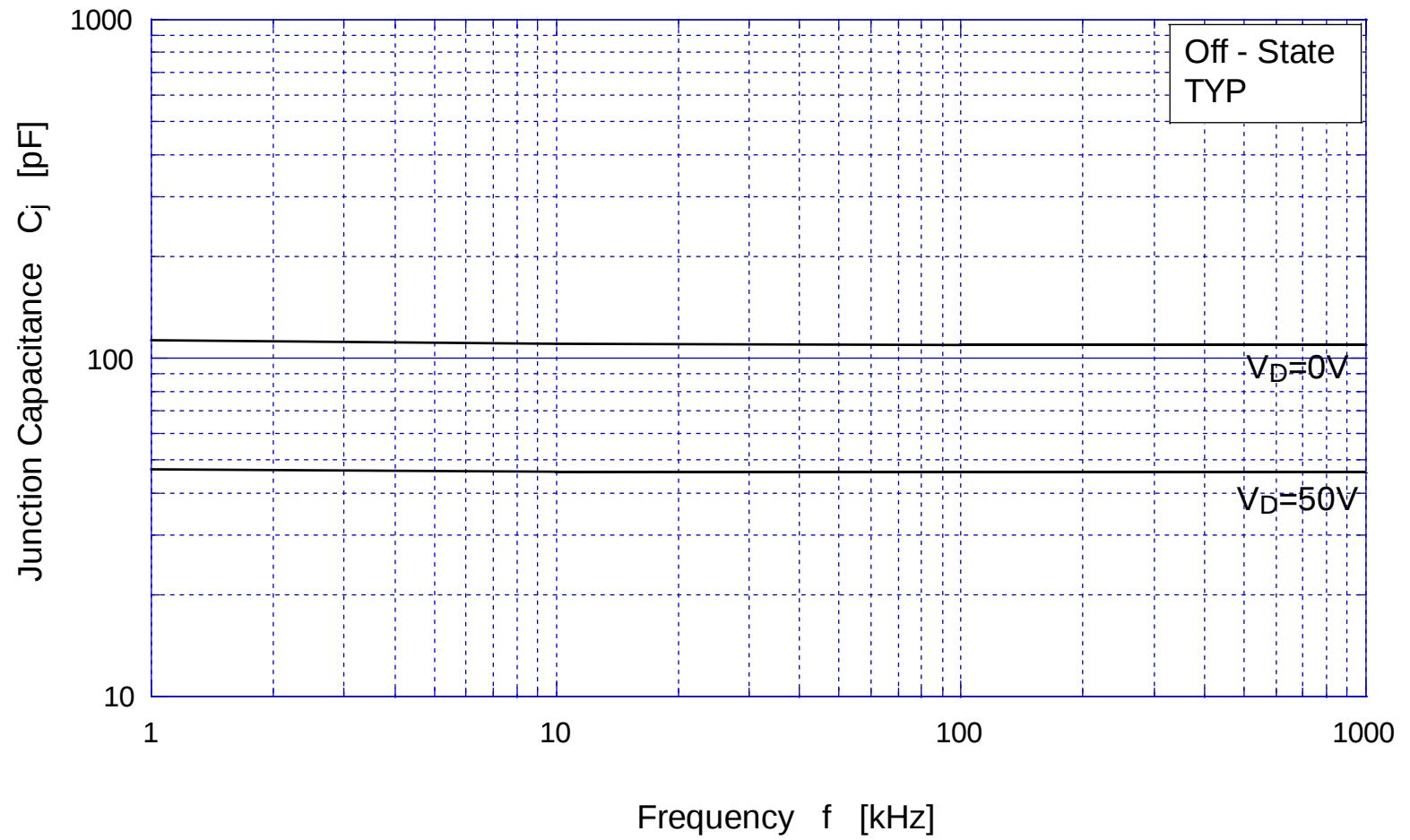
KT10R25 Break Over Voltage vs Junction Temperature



KT10R25 Holding Current vs Junction Temperature



KT10R25 Junction Capacitance



KT10R25 Junction Capacitance

